NSN 5962-01-247-1358

Memory Microcircuit - Page 1 of 1



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Body L	ength:
- 1.290 in	-
Body W	/idth:
0.560 in	
Body H	
0.180 in	
Maximu	Im Power Dissipation Rating:
420.0 m	
Operati	ng Tempurature Range:
	25.0 degrees celsius
	e Tempurature Range:
	150.0 degrees celsius
Feature	es Provided:
Hermeti	cally sealed and programmable and w/resistor and positive outputs
	re Material:
Ceramio	
Inclosu	re Configuration:
Dual-in-	
Output	Logic Form:
Transis	or-transistor logic
Input C	ircuit Pattern:
8 input	
Termin	al Surface Treatment:
Solder	
Voltage	Rating And Type Per Characteristic:
7.0 volts	s power source
Time R	ating Per Chacteristic:
100.00	nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output	
Memory	y Device Type:
Rom	
Memory	y Capacity:
Unknow	'n
Termin	al Type And Quantity:
20 print	ed circuit
Shelf Li	ife:
N/a	
Unit Of	Measure:
Demilit	arization:
Yes - de	emil/mli
Fiig:	
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